## SUBJECT NO-EC29205, SUBJECT NAME- DEVICES LABORATORY

LTP- 0-0-3,CRD- 2

## SYLLABUS :-

1. JFET Characterization2. Diode Breakdown Characteristics3. Capacitance âVoltage Characteristics of a PN Junction (Doping profile)4. High frequency Characteristics of BJT.5. SCR Characteristics.6. Hall Effect.